

IGBT4 Modules

SKM400GAR17E4

Features*

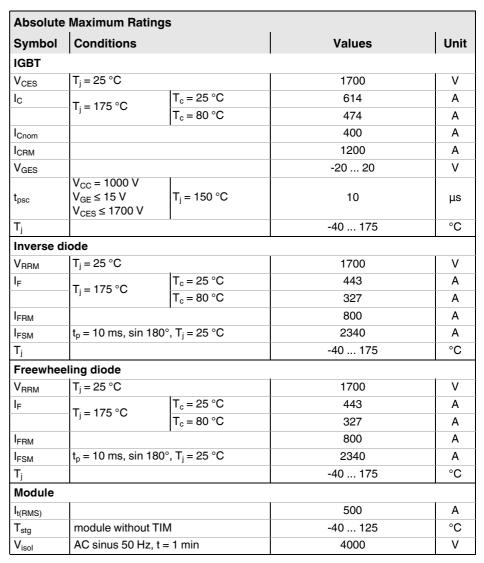
- IGBT4 = 4th generation medium fast trench IGBT (Infineon)
- CAL4 = Soft switching 4th generation CAL-Diode
- Insulated copper baseplate using DBC Technology (Direct Copper Bonding)
- · With integrated Gate resistor
- For switching frequencies up to 8kHz
- UL recognized, file no. E63532

Typical Applications

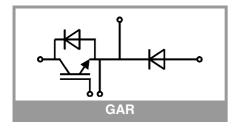
- · Electronic welders
- DC/DC converter
- · Brake chopper
- · Switched reluctance motor

Remarks

- Case temperature limited to T_C = 125°C max.
- Recommended $T_{j,op} = -40 \dots +150$ °C
- Product reliability results valid for T_j = 150°C



Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
IGBT						•
• C⊏(Sat)	I _C = 400 A	T _j = 25 °C		1.92	2.20	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.30	2.60	V
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V
	Chipievei	T _j = 150 °C		0.70	0.80	V
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		2.8	3.3	mΩ
		T _j = 150 °C		4.0	4.5	mΩ
$V_{GE(th)}$	V _{GE} =V _{CE} , I _C = 16 mA		5.2	5.8	6.4	V
I _{CES}	V _{GE} = 0 V, V _{CE} = 1700 V, T _j = 25 °C				5	mA
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		32.0		nF
Coes		f = 1 MHz		1.36		nF
C _{res}		f = 1 MHz		1.16		nF
Q_G	V _{GE} = - 8 V+ 15 V			3200		nC
R _{Gint}	T _j = 25 °C			1.9		Ω





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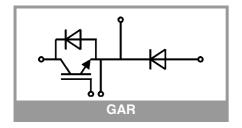
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Characte	ristics					
Symbol	Conditions		min.	typ.	max.	Unit
IGBT				•		
t _{d(on)}	V _{CC} = 1200 V	T _j = 150 °C		280		ns
t _r	$I_{\rm C} = 400 {\rm A}$	T _j = 150 °C		45		ns
E _{on}	$V_{GE} = +15/-15 \text{ V}$ $R_{G \text{ on}} = 2 \Omega$	T _j = 150 °C		157		mJ
t _{d(off)}	$R_{G \text{ off}} = 1 \Omega$	T _i = 150 °C		760		ns
t _f	di/dt _{on} = 10000 A/	T _j = 150 °C		140		ns
E _{off}	μs di/dt _{off} = 2300 A/μs dv/dt = 5600 V/μs	T _j = 150 °C		180		mJ
R _{th(j-c)}	per IGBT				0.066	K/W
R _{th(c-s)}	per IGBT, P12 (reference)			0.036		K/W
R _{th(c-s)}	per IGBT, HP-PCM			0.019		K/W
Inverse d	iode					
$V_F = V_{EC}$	I _F = 400 A	T _j = 25 °C		2.00	2.40	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.16	2.57	٧
V _{F0}	chiplevel	T _j = 25 °C		1.32	1.56	V
		T _j = 150 °C		1.08	1.22	V
r _F	chiplevel	T _j = 25 °C		1.71	2.1	mΩ
		T _j = 150 °C		2.7	3.4	mΩ
I _{RRM}	I _F = 400 A	T _j = 150 °C		615		Α
Q _{rr}	di/dt _{off} = 10100 A/	T _j = 150 °C		150		μC
Err	μs V _{GE} = -15 V V _{CC} = 1200 V	T _j = 150 °C		130		mJ
R _{th(j-c)}	per diode				0.13	K/W
R _{th(c-s)}	per diode, P12 (reference)			0.044		K/W
R _{th(c-s)}	per diode, HP-PCM	per diode, HP-PCM		0.027		K/W
Freewhee	eling diode					
$V_F = V_{EC}$	I _F = 400 A	T _j = 25 °C		2.00	2.40	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.16	2.57	٧
V_{F0}	chiplevel	T _j = 25 °C		1.32	1.56	V
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r _F	chiplevel	T _j = 25 °C		1.71	2.1	mΩ
	Chipievei	T _j = 150 °C		2.7	3.4	mΩ
I _{RRM}	I _F = 400 A	T _j = 150 °C		615		Α
Q _{rr}	$di/dt_{off} = 10100 \text{ A/}$ μs	T _j = 150 °C		150		μC
E _{rr}	$V_{GE} = -15 \text{ V}$ $V_{CC} = 1200 \text{ V}$	T _j = 150 °C		130		mJ
R _{th(j-c)}	per diode				0.13	K/W
R _{th(c-s)}	per diode, P12 (reference)			0.044		K/W
R _{th(c-s)}	per diode, HP-PCM	per diode, HP-PCM		0.027		K/W





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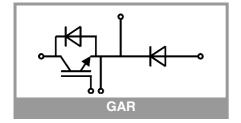
Typical Applications

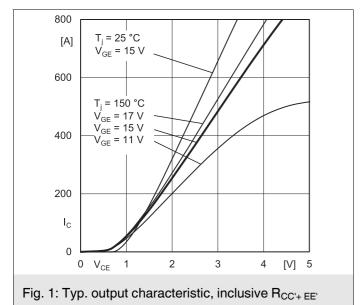
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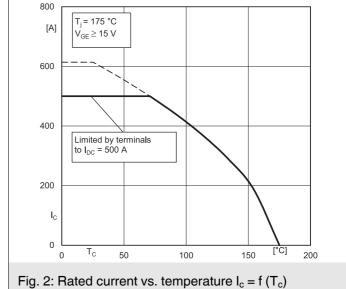
Remarks

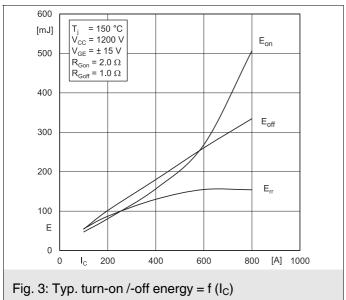
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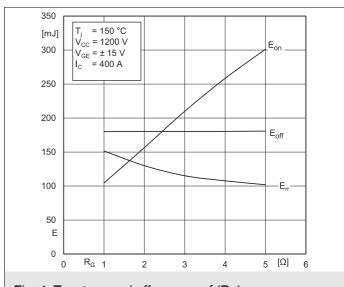
Characteristics							
Symbol	Conditions	min.	typ.	max.	Unit		
Module							
L _{CE}				15		nΗ	
R _{CC'+EE'}	measured per switch	T _C = 25 °C		0.55		mΩ	
		T _C = 125 °C		0.85		mΩ	
R _{th(c-s)1}	calculated without thermal coupling			0.0198		K/W	
R _{th(c-s)2}	including thermal coupling, T _s underneath module, P12 (reference)		0.0201			K/W	
R _{th(c-s)2}	including thermal coupling, T _s underneath module, HP-PCM			0.0113		K/W	
Ms	to heat sink M6		3		5	Nm	
Mt		to terminals M6	2.5		5	Nm	
						Nm	
W					325	g	

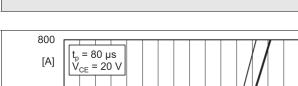


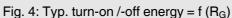


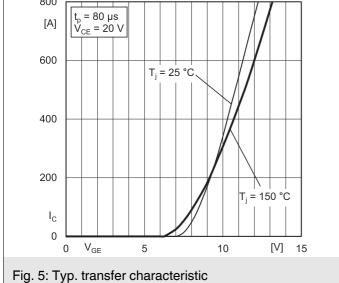












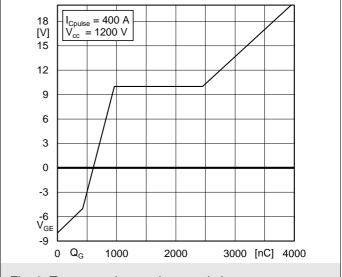
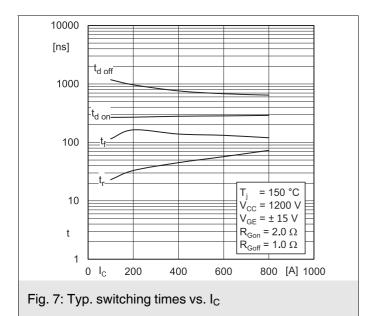
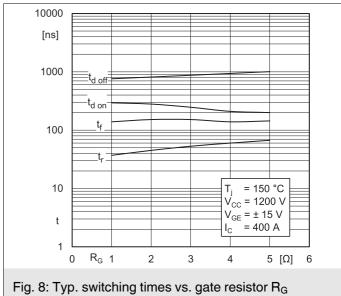
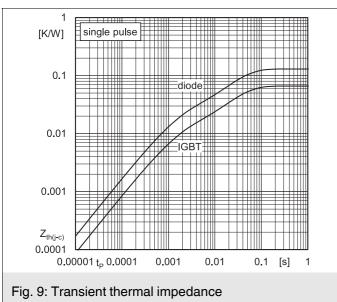


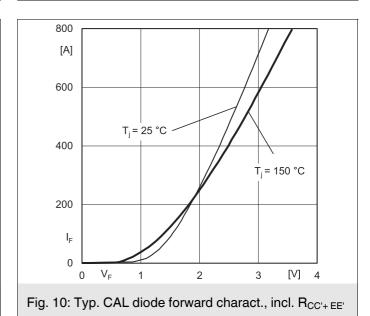
Fig. 6: Typ. gate charge characteristic

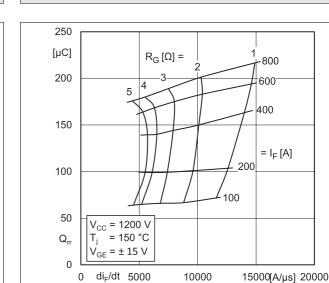












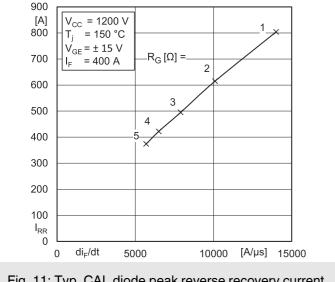
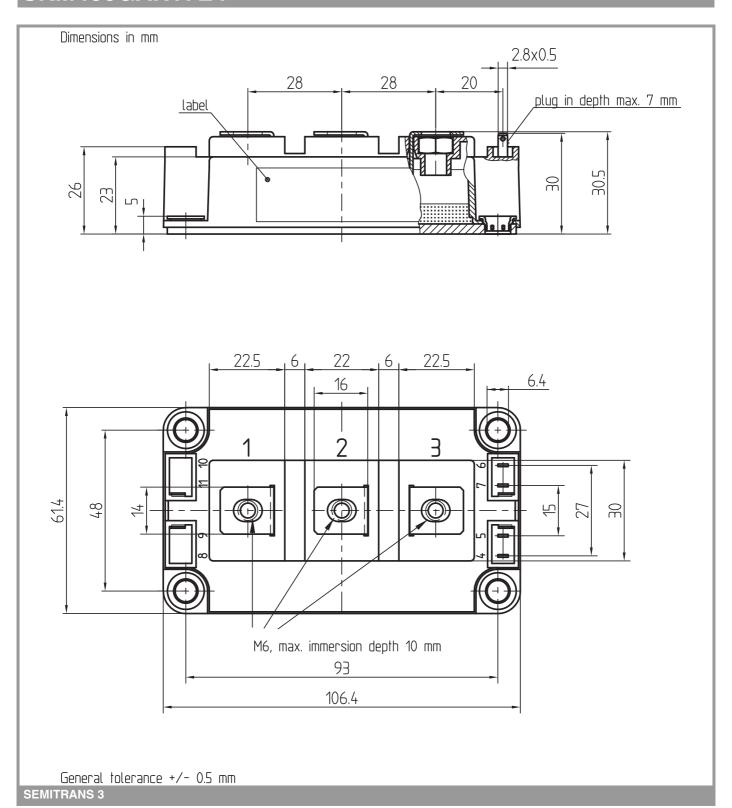
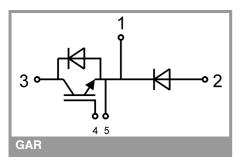


Fig. 11: Typ. CAL diode peak reverse recovery current

Fig. 12: Typ. CAL diode peak reverse recovery charge





IMPORTANT INFORMATION AND WARNINGS

This is an electrostatic discharge sensitive device (ESDS) according to international standard IEC 61340.

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